Vishay Semiconductors

SCR/SCR and SCR/Diode (MAGN-A-PAK Power Modules), 230 A



MAGN-A-PAK

230 A

FEATURES

- High voltage
- Electrically isolated base plate
- 3500 V_{RMS} isolating voltage
- Industrial standard package
- · Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

This new VSK series of MAGN-A-PAK modules uses high voltage power thyristor/thyristor and thyristor/diode in seven basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges or as AC-switches when modules are connected in anti-parallel mode. These modules are intended for general purpose applications such as battery chargers, welders, motor drives, UPS, etc.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{T(AV)}	85 °C	230					
I _{T(RMS)}		510	A				
	50 Hz	7500	A				
I _{TSM}	60 Hz	7850					
l ² t	50 Hz	280	kA ² s				
1-1	60 Hz	260	KA-S				
l²√t		280	kA²√s				
V _{DRM} /V _{RRM}		Up to 2000	V				
TJ	Range	- 40 to 130	°C				

ELECTRICAL SPECIFICATIONS

PRODUCT SUMMARY

I_{T(AV)}

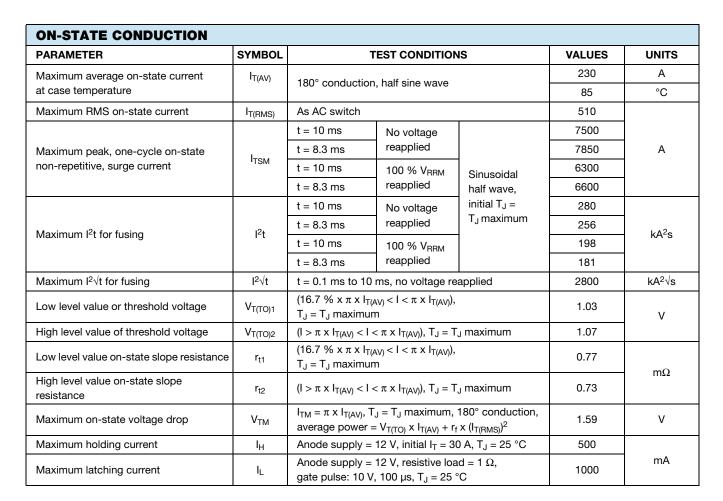
VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK REVERSE AND OFF-STATE BLOCKING VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 130 °C MAXIMUM mA			
	08	800	900				
	12	1200	1300				
VSK.230-	16	1600	1700	50			
	18	1800	1900				
	20	2000	2100				

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VSK.230..PbF Series

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SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical delay time	t _d	$T_J = 25 \text{ °C}$, gate current = 1 A dI _d /dt = 1 A/µs	1.0			
Typical rise time	t _r	V _d = 0.67 % V _{DRM}	2.0	μs		
Typical turn-off time	tq	I_{TM} = 300 A; dl/dt = 15 A/μs; T _J = T _J maximum; V _R = 50 V; dV/dt = 20 V/μs; gate 0 V, 100 Ω	50 to 150	μο		

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum	50	mA			
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted, 25 $^{\circ}\text{C},$ 1 s	3000	V			
Critical rate of rise of off-state voltage	dV/dt	$T_{\rm J}$ = $T_{\rm J}$ maximum, exponential to 67 % rated V_{DRM}	1000	V/µs			

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TRIGGERING						
PARAMETER	SYMBOL	DL TEST CONDITIONS		VALUES	UNITS	
Maximum peak gate power	P _{GM}	$t_p \le 5 \text{ ms}, \text{ T}_J = \text{T}_J \text{ r}$	naximum	10.0	w	
Maximum average gate power	P _{G(AV)}	$f = 50 \text{ Hz}, \text{ T}_{\text{J}} = \text{T}_{\text{J}} \text{ r}$	naximum	2.0	vv	
Maximum peak gate current	+ I _{GM}	$t_p \le 5 \text{ ms}, T_J = T_J r$	naximum	3.0	А	
Maximum peak negative gate voltage	- V_{GT} $t_p \le 5 \text{ ms}, T_J = T_J \text{ maximum}$		5.0			
		T _J = - 40 °C	Anode supply = 12 V, resistive load; Ra = 1 Ω	4.0	V	
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C		3.0		
		$T_J = T_J maximum$		2.0		
		T _J = - 40 °C	Anode supply = 12 V, resistive load; Ra = 1 Ω	350		
Maximum required DC gate current to trigger	I _{GT}	T _J = 25 °C		200	mA	
		$T_J = T_J$ maximum	103131100 1040, 114 - 1 32	100		
Maximum gate voltage that will not trigger	V _{GD}	$T_J = T_J$ maximum, rated V_{DRM} applied		0.25	V	
Maximum gate current that willnot trigger	I _{GD}	$T_J = T_J$ maximum, rated V_{DRM} applied		10.0	mA	
Maximum rate of rise of turned-on current	dl/dt	$T_J = T_J$ maximum, $I_{TM} = 400$ A, rated V _{DRM} applied		500	A/µs	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Junction operating temperature range		TJ		- 40 to 130	°C	
Storage temperature range	e	T _{Stg}		- 40 to 150	U	
Maximum thermal resistance, junction to case per junction		R _{thJC}	DC operation	0.125	K/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.02		
Mounting torque ± 10 %	MAP to heatsink		A mounting compound is recommended and the torque should be rechecked after a	4 to 6	Nm	
	busbar to MAP		period of about 3 h to allow for the spread of the compound.	4 10 0	NIII	
Approximate weight				500	g	
Approximate weight				17.8	oz.	
Case style				MAGN	A-PAK	

DEVICES	SINUS	DIDAL CON	DUCTION	I AT T _J MA	хімим	RECTANGULAR CONDUCTION AT T _J MAXIMUM				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30 °	UNITS
VSK.230-	0.009	0.010	0.010	0.020	0.032	0.007	0.011	0.015	0.020	0.033	K/W

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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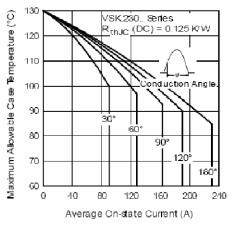
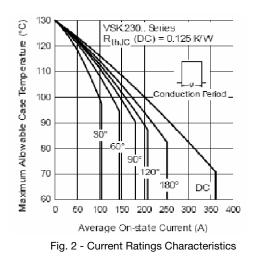


Fig. 1 - Current Ratings Characteristics



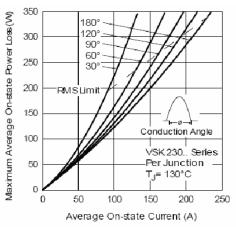


Fig. 3 - On-State Power Loss Characteristics

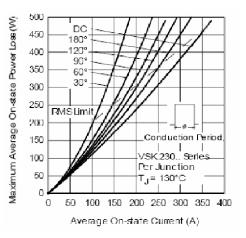


Fig. 4 - On-State Power Loss Characteristics

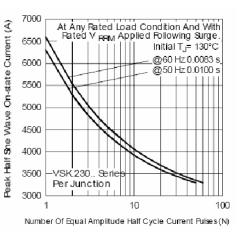


Fig. 5 - Maximum Non-Repetitive Surge Current

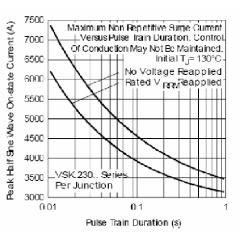


Fig. 6 - Maximum Non-Repetitive Surge Current

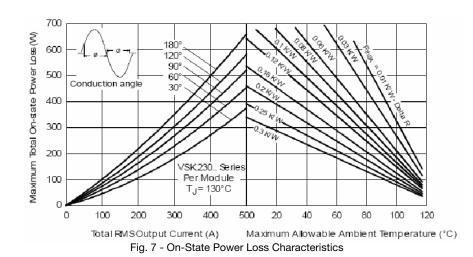
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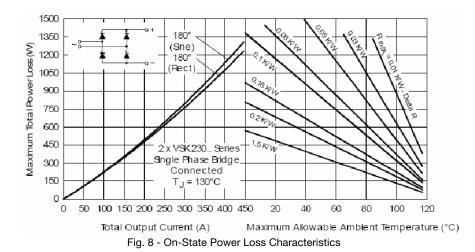
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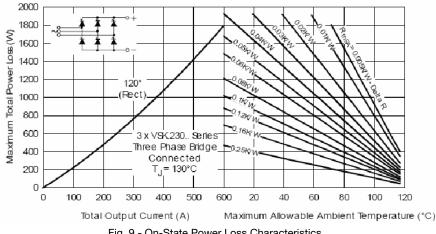


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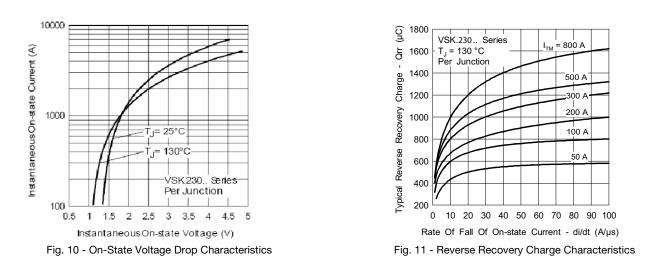




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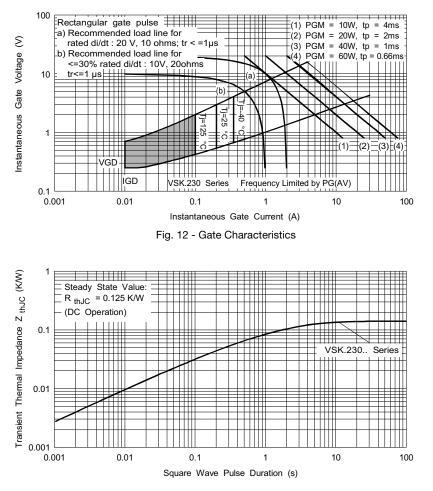


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

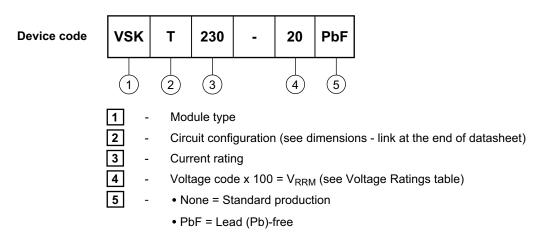
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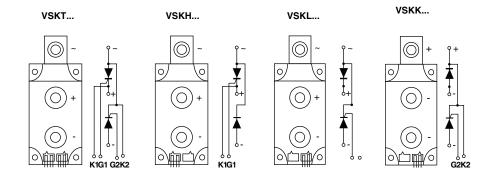
ORDERING INFORMATION TABLE



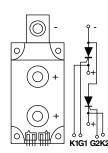
Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

CIRCUIT CONFIGURATION



VSKV...



Available 800 V; contact factory for different requirements.

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95086			

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